

SCDS113D-DECEMBER 2002-REVISED APRIL 2005

### FEATURES

- High-Bandwidth Data Path (up to 500 MHz (1))
- 5-V-Tolerant I/Os With Device Powered Up or Powered Down
- Low and Flat ON-State Resistance (r<sub>on</sub>) Characteristics Over Operating Range (r<sub>on</sub> = 4 Ω Typ)
- Rail-to-Rail Switching on Data I/O Ports
   0- to 5-V Switching With 3.3-V V<sub>CC</sub>
  - 0- to 3.3-V Switching With 2.5-V  $\rm V_{\rm CC}$
- Bidirectional Data Flow With Near-Zero Propagation Delay
- Low Input/Output Capacitance Minimizes Loading and Signal Distortion (C<sub>io(OFF)</sub> = 3.5 pF Typ)
- Fast Switching Frequency (f<sub>DE</sub> = 20 MHz Max)
- For additional information regarding the performance characteristics of the CB3Q family, refer to the TI application report, *CBT-C*, *CB3T*, and *CB3Q Signal-Switch Families*, literature number SCDA008.

- Data and Control Inputs Provide Undershoot Clamp Diodes
- Low Power Consumption (I<sub>cc</sub> = 0.25 mA Typ)
- V<sub>cc</sub> Operating Range From 2.3 V to 3.6 V
- Data I/Os Support 0- to 5-V Signaling Levels (0.8 V, 1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.3 V, 5 V)
- Control Inputs Can Be Driven by TTL or 5-V/3.3-V CMOS Outputs
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA
  Per JESD 78, Class II
- ESD Performance Tested Per JESD 22

   2000-V Human-Body Model
  - (A114-B, Class II)
    - 1000-V Charged-Device Model (C101)
- Supports Both Digital and Analog Applications: USB Interface, Differential Signal Interface, Bus Isolation, Low-Distortion Signal Gating

PW PACKAGE (TOP VIEW)

1 <u>0</u> E [ 1A [ 1B [	1 2	U	8 7	] V <sub>CC</sub> ] 2OE
1B [ GND [	3 4		6 5	2B

## **DESCRIPTION/ORDERING INFORMATION**

The SN74CB3Q3306A is a high-bandwidth FET bus switch utilizing a charge pump to elevate the gate voltage of the pass transistor, providing a low and flat ON-state resistance ( $r_{on}$ ). The low and flat ON-state resistance allows for minimal propagation delay and supports rail-to-rail switching on the data input/output (I/O) ports. The device also features low data I/O capacitance to minimize capacitive loading and signal distortion on the data bus. Specifically designed to support high-bandwidth applications, the SN74CB3Q3306A provides an optimized interface solution ideally suited for broadband communications, networking, and data-intensive computing systems.

The SN74CB3Q3306A is organized as two 1-bit switches with separate output-enable  $(1\overline{OE}, 2\overline{OE})$  inputs. It can be used as two 1-bit bus switches or as one 2-bit bus switch. When  $\overline{OE}$  is low, the associated 1-bit bus switch is ON and the A port is connected to the B port, allowing bidirectional data flow between ports. When  $\overline{OE}$  is high, the associated 1-bit bus switch is OFF and a high-impedance state exists between the A and B ports.

#### **ORDERING INFORMATION**

T <sub>A</sub>	PAC	KAGE <sup>(1)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
40°C to 95°C	TSSOP – PW	Tube	SN74CB3Q3306APW	- BU306A	
–40°C to 85°C	1550P - PW	Tape and reel	SN74CB3Q3306APWR		

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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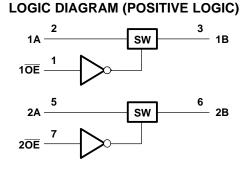
### **DESCRIPTION/ORDERING INFORMATION (CONTINUED)**

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry prevents damaging current backflow through the device when it is powered down. The device has isolation during power off.

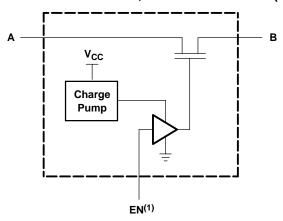
To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to V<sub>CC</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

#### FUNCTION TABLE (EACH BUS SWITCH)

	INPUT/OUTPUT A	FUNCTION
L	В	A port = B port
н	Z	Disconnect



### SIMPLIFIED SCHEMATIC, EACH FET SWITCH (SW)



(1) EN is the internal enable signal applied to the switch.

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# Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	4.6	V
$V_{IN}$	Control input voltage range <sup>(2)(3)</sup>		-0.5	7	V
V <sub>I/O</sub>	Switch I/O voltage range <sup>(2)(3)(4)</sup>		-0.5	7	V
I <sub>IK</sub>	Control input clamp current	V <sub>IN</sub> < 0		-50	mA
I <sub>I/OK</sub>	I/O port clamp current	V <sub>I/O</sub> < 0		-50	mA
I <sub>I/O</sub>	ON-state switch current <sup>(5)</sup>			±64	mA
	Continuous current through each $V_{CC}$ or GND			±100	mA
$\theta_{JA}$	Package thermal impedance <sup>(6)</sup>			88	°C/W
T <sub>stg</sub>	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltages are with respect to ground, unless otherwise specified.

(3) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

(4)  $V_1$  and  $V_0$  are used to denote specific conditions for  $V_{1/0}$ .

(5)  $I_{\rm I}$  and  $I_{\rm O}$  are used to denote specific conditions for  $I_{\rm I/O}$ .

(6) The package thermal impedance is calculated in accordance with JESD 51-7.

### **Recommended Operating Conditions**<sup>(1)</sup>

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2.3	3.6	V
V		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	5.5	V
V <sub>IH</sub>	High-level control input voltage	$V_{CC} = 2.7 V \text{ to } 3.6 V$	2	5.5	v
V	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0	0.7	V
VIL	Low-level control input voltage	V <sub>CC</sub> = 2.7 V to 3.6 V	0	0.8	v
V <sub>I/O</sub>	Data input/output voltage		0	5.5	V
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

 All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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### Electrical Characteristics<sup>(1)</sup>

over recommended operating free-air temperature range (unless otherwise noted)

PA	RAMETER		TEST CONDITIO	NS	MIN TYP <sup>(2)</sup>	MAX	UNIT	
V <sub>IK</sub>		V <sub>CC</sub> = 3.6 V,	I <sub>I</sub> = -18 mA			-1.8	V	
I <sub>IN</sub>	Control inputs	V <sub>CC</sub> = 3.6 V,	$V_{IN} = 0$ to 5.5 V			±1	μA	
I <sub>OZ</sub> <sup>(3)</sup>		V <sub>CC</sub> = 3.6 V,	$V_{O} = 0$ to 5.5 V, $V_{I} = 0$ ,	Switch OFF, $V_{IN} = V_{CC}$ or GND		±1	μA	
I <sub>off</sub>		$V_{CC} = 0,$	$V_{\rm O} = 0$ to 5.5 V,	V <sub>I</sub> = 0		1	μA	
I <sub>CC</sub>		V <sub>CC</sub> = 3.6 V,	$I_{I/O} = 0,$ Switch ON or OFF,	$V_{IN} = V_{CC}$ or GND	0.25	0.7	mA	
$\Delta I_{CC}^{(4)}$	Control inputs	V <sub>CC</sub> = 3.6 V,	One input at 3 V,	Other inputs at $V_{CC}$ or GND		25	μA	
I <sub>CCD</sub> <sup>(5)</sup>	Per control input	V <sub>CC</sub> = 3.6 V, Control input switching	A and B ports open,		0.03	0.1	mA/ MHz	
C <sub>in</sub>	Control inputs	$V_{\rm CC} = 3.3 \text{ V},$	$V_{IN} = 5.5 \text{ V}, 3.3 \text{ V}, \text{ or}$	0	2.5	3.5	pF	
C <sub>io(OFF)</sub>		V <sub>CC</sub> = 3.3 V,	Switch OFF, $V_{IN} = V_{CC}$ or GND,	$V_{I/O} = 5.5 V, 3.3 V, \text{ or } 0$	3.5	5	pF	
C <sub>io(ON)</sub>		V <sub>CC</sub> = 3.3 V,	Switch ON, $V_{IN} = V_{CC}$ or GND,	$V_{I/O} = 5.5 V, 3.3 V, \text{ or } 0$	8	10.5	pF	
		V <sub>CC</sub> = 2.3 V,	$V_{I} = 0,$	I <sub>O</sub> = 30 mA	4	8		
- (6)		$TYP$ at $V_{CC} = 2.5 V$	V <sub>I</sub> = 1.7 V,	I <sub>O</sub> = -15 mA	5	9	9 Ω	
r <sub>on</sub> (6)		V - 2 V	$V_{I} = 0,$	I <sub>O</sub> = 30 mA	4	6	12	
		$V_{CC} = 3 V$	V <sub>I</sub> = 2.4 V,	I <sub>O</sub> = -15 mA	5	8		

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(1)

 $V_{IN}$  and  $I_{IN}$  refer to control inputs.  $V_{I},\,V_{O},\,I_{I}$ , and  $I_{O}$  refer to data pins. All typical values are at  $V_{CC}$  = 3.3 V (unless otherwise noted),  $T_{A}$  = 25°C. For I/O ports, the parameter  $I_{OZ}$  includes the input leakage current. (2)

(3)

This is the increase in supply current for each input that is at the specified TTL voltage level, rather than  $V_{CC}$  or GND. (4)

This parameter specifies the dynamic power-supply current associated with the operating frequency of a single control input (see (5) Figure 2).

Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is (6) determined by the lower of the voltages of the two (A or B) terminals.

### Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER		TO (OUTPUT)	V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		UNIT
	(INPUT)		MIN	MAX	MIN	MAX	
f <sub>OE</sub> <sup>(1)</sup>	ŌĒ	A or B		10		20	MHz
t <sub>pd</sub> <sup>(2)</sup>	A or B	B or A		0.2		0.2	ns
t <sub>en</sub>	OE	A or B	1.5	6.5	1.5	5.5	ns
t <sub>dis</sub>	OE	A or B	1	6	1	5	ns

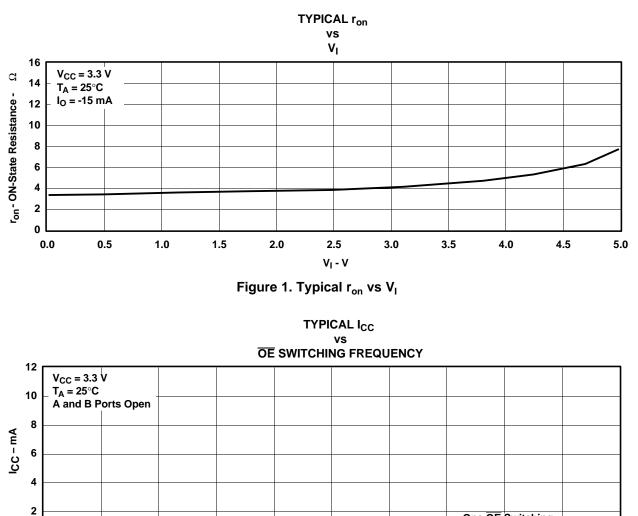
(1) Maximum switching frequency for control input ( $V_O > V_{CC}$ ,  $V_I = 5 V$ ,  $R_L \ge 1 M\Omega$ ,  $C_L = 0$ ) (2) The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

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# SN74CB3Q3306A DUAL FET BUS SWITCH 2.5-V/3.3-V LOW-VOLTAGE HIGH-BANDWIDTH BUS SWITCH

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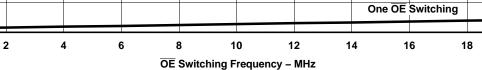


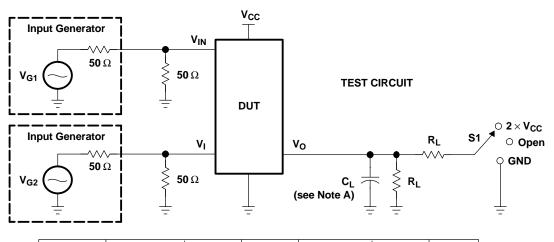
Figure 2. Typical I<sub>CC</sub> vs OE Switching Frequency

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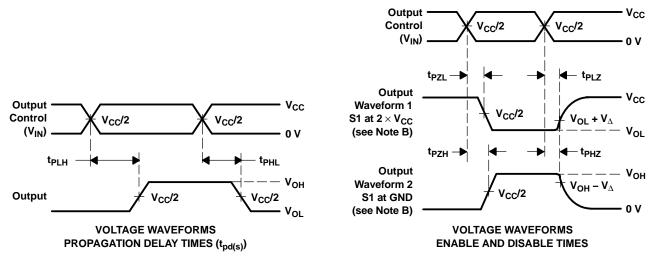
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#### PARAMETER MEASUREMENT INFORMATION



TEST	V <sub>cc</sub>	S1	RL	VI	CL	$V_{\Delta}$
t <sub>pd(s)</sub>	$\textbf{2.5 V} \pm \textbf{0.2 V}$	Open	<b>500</b> Ω	V <sub>CC</sub> or GND	30 pF	
	$\textbf{3.3 V} \pm \textbf{0.3 V}$	Open	<b>500</b> Ω	V <sub>CC</sub> or GND	50 pF	
t <sub>PLZ</sub> /t <sub>PZL</sub>	$\textbf{2.5 V} \pm \textbf{0.2 V}$	2 × V <sub>CC</sub>	<b>500</b> Ω	GND	30 pF	0.15 V
'ዋር2' 'ዋ2ር	3.3 V $\pm$ 0.3 V	$2 \times V_{CC}$	<b>500</b> Ω	GND	50 pF	0.3 V
+/+	$2.5$ V $\pm$ 0.2 V	GND	<b>500</b> Ω	v <sub>cc</sub>	30 pF	0.15 V
t <sub>PHZ</sub> /t <sub>PZH</sub>	3.3 V $\pm$ 0.3 V	GND	<b>500</b> Ω	V <sub>CC</sub>	50 pF	0.3 V



NOTES: A.  $C_L$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>Q</sub> = 50  $\Omega$ , t<sub>r</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd(s)}$ . The  $t_{pd}$  propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
- H. All parameters and waveforms are not applicable to all devices.

#### Figure 3. Test Circuit and Voltage Waveforms

TEXAS

### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
74CB3Q3306ADCURE4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74CB3Q3306ADCURG4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74CB3Q3306APWRE4	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3Q3306ADCUR	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3Q3306APW	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3Q3306APWE4	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3Q3306APWG4	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3Q3306APWR	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3Q3306APWRG4	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. **TBD:** The Pb-Free/Green conversion plan has not been defined.

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Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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## TAPE AND REEL INFORMATION





# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

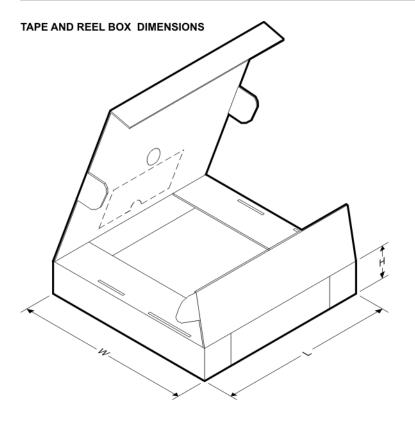


*All dimensions are nominal												
Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74CB3Q3306ADCUR	US8	DCU	8	3000	180.0	9.2	2.25	3.35	1.05	4.0	8.0	Q3
SN74CB3Q3306APWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1



# PACKAGE MATERIALS INFORMATION

11-Mar-2008



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74CB3Q3306ADCUR	US8	DCU	8	3000	202.0	201.0	28.0
SN74CB3Q3306APWR	TSSOP	PW	8	2000	346.0	346.0	29.0

# **MECHANICAL DATA**

MTSS001C - JANUARY 1995 - REVISED FEBRUARY 1999

# PW (R-PDSO-G\*\*)

#### PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-187 variation CA.



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